NSN 5962-01-363-6480

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Milstar
Features Provided:
Hermetically sealed and radiation hardened
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-10 mil-m-38510
Product Name:
Mckt, digital, memory, nmos, eeprom, 32k x 8
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Eeprom
Special Features:
Esd; hci. Selected from p/n 49956 g431118-1. Mfg 60395 x28256dmb-25
Terminal Type And Quantity:
28 beam lead
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig:
A458a0